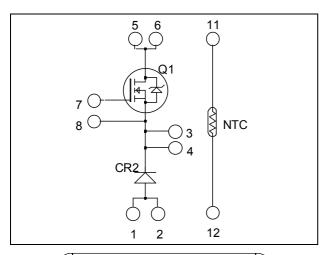
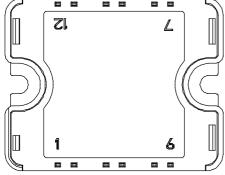


# Buck chopper MOSFET Power Module

$$\begin{split} V_{DSS} &= 1200V \\ R_{DSon} &= 560 \text{m}\Omega \text{ typ @ Tj} = 25^{\circ}\text{C} \\ I_D &= 18\text{A @ Tc} = 25^{\circ}\text{C} \end{split}$$





Pins 1/2; 3/4; 5/6 must be shorted together

#### Application

- AC and DC motor control
- Switched Mode Power Supplies

#### **Features**

- Power MOS 8<sup>TM</sup> MOSFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Very rugged
- Very low stray inductance
- Internal thermistor for temperature monitoring
- High level of integration

#### **Benefits**

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Solderable terminals both for power and signal for easy PCB mounting
- Low profile
- RoHS Compliant

#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		1200	V
T	Continuous Drain Current	$T_c = 25^{\circ}C$	18	
$I_D$	Continuous Drain Current	$T_c = 80$ °C	13	A
$I_{DM}$	Pulsed Drain current		104	
$V_{GS}$	Gate - Source Voltage		±30	V
R <sub>DSon</sub>	Drain - Source ON Resistance		672	mΩ
$P_{\mathrm{D}}$	Maximum Power Dissipation	$T_c = 25^{\circ}C$	390	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		14	A

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



### All ratings @ $T_j = 25$ °C unless otherwise specified

### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
T	Zero Gate Voltage Drain Current	$V_{\rm DS} = 1200 \rm V$	$T_j = 25$ °C			100	^
$I_{\mathrm{DSS}}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V$	$T_j = 125$ °C			500	μΑ
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 14A$			560	672	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 2.5 \text{mA}$		3	4	5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}$				±100	nA

**Dynamic Characteristics** 

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		7736		
$C_{oss}$	Output Capacitance	$V_{\rm DS} = 25V$		715		pF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		92		
$Q_{g}$	Total gate Charge	$V_{GS} = 10V$		300		
$Q_{gs}$	Gate – Source Charge	$V_{Bus} = 600V$		50		nC
$Q_{\mathrm{gd}}$	Gate – Drain Charge	$I_{D} = 14A$		140		
$T_{d(on)}$	Turn-on Delay Time	Resistive switching @ 25°C		50		
$T_{\rm r}$	Rise Time	$\begin{split} V_{GS} &= 15 V \\ V_{Bus} &= 800 V \\ I_D &= 14 A \\ R_G &= 2.2 \Omega \end{split}$		31		
$T_{d(off)}$	Turn-off Delay Time			170		ns
$T_{\mathrm{f}}$	Fall Time			48		

Chopper diode ratings and characteristics

Symbol	Characteristic		Test Conditions		Тур	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1200			V
$I_{RM}$	Maximum Reverse Leakage Current	V <sub>R</sub> =1200V	$T_i = 25^{\circ}C$ $T_i = 125^{\circ}C$			100 500	μΑ
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		30		A
	Diode Forward Voltage	$I_F = 30A$			2.6	3.1	
$V_{\rm F}$		$I_F = 60A$			3.2		V
		$I_F = 30A$	$T_{i} = 125^{\circ}C$		1.8		
t	Reverse Recovery Time		$T_j = 25$ °C		300		ns
$t_{rr}$	$I_{F} = 30A$ $V_{R} = 800V$	$I_F = 30A$	$T_j = 125$ °C		380		115
	Reverse Recovery Charge	$di/dt = 200A/\mu s$ $T_j = 25^{\circ}C$	$T_j = 25$ °C		360		nC
Q <sub>rr</sub>			$T_{j} = 125^{\circ}C$		1700		IIC

Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
P	Junction to Case Thermal Resistance	T	ransistor			0.32	
$R_{thJC}$		D	iode			1.2	°C/W
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{\rm J}$	Operating junction temperature range			-40		150	
$T_{STG}$	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature					100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight		•			80	g

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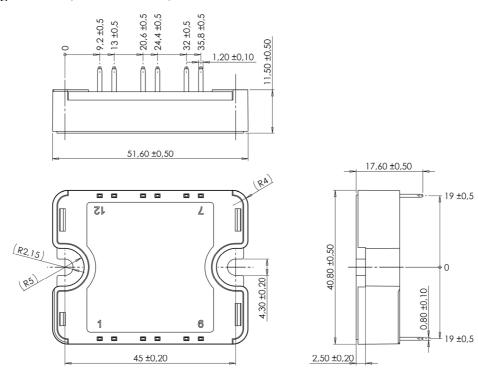


Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

Symbol	Characteristic	Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C		50		kΩ
B 25/85	$T_{25} = 298.15 \text{ K}$		3952		K

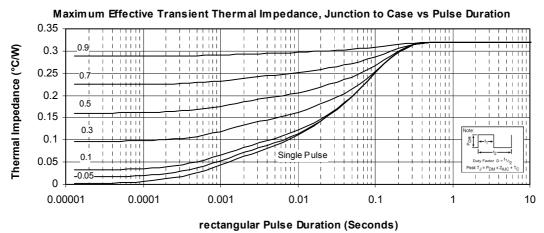
$$R_{T} = \frac{R_{25}}{\exp \left[ B_{25/85} \left( \frac{1}{T_{25}} - \frac{1}{T} \right) \right]} \quad \text{T: Thermistor temperature}$$
 
$$R_{T}: \text{ Thermistor value at T}$$

### SP1 Package outline (dimensions in mm)

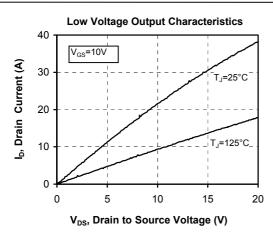


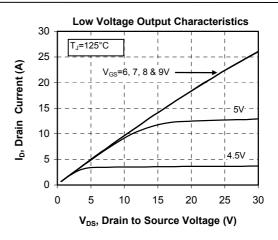
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

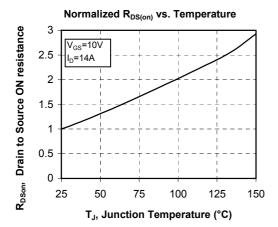
### **Typical Mosfet Performance Curve**

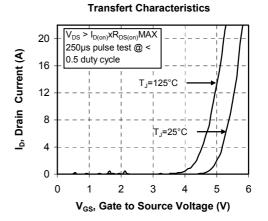


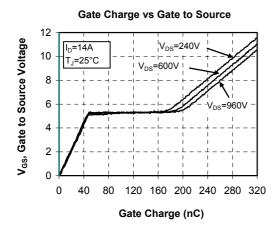


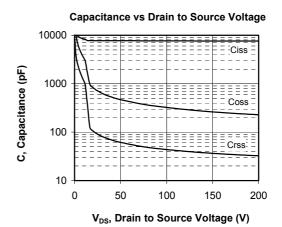






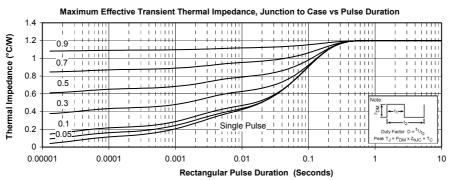


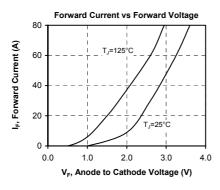


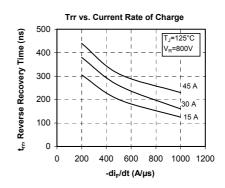


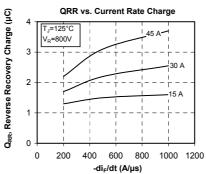


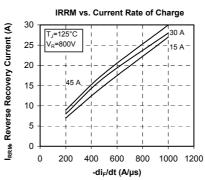
#### **Typical Diode Performance Curve**

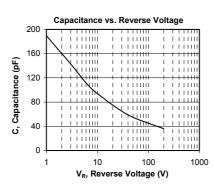


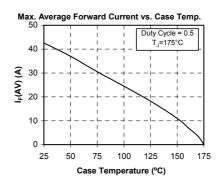












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